

# **isc** Silicon NPN Power Transistor

2SC4381

#### **DESCRIPTION**

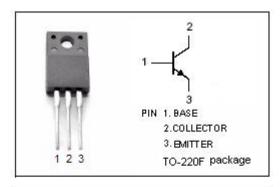
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 150V(Min)
- DC Current Gain-
  - :  $h_{FE}$ = 60(Min)@ ( $V_{CE}$ = 10V,  $I_{C}$ = 0.7A)
- Complement to Type 2SA1667
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

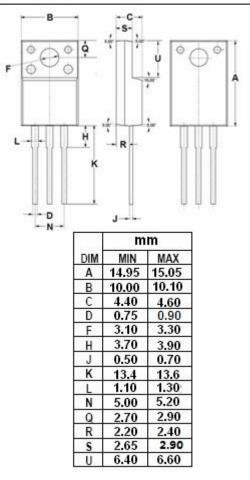
### **APPLICATIONS**

 Designed for TV vertical output ,audio output driver and general purpose applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	150	V	
Vceo	Collector-Emitter Voltage	150	V	
V <sub>EBO</sub>	Emitter-Base Voltage	6	V	
Ic	Collector Current-Continuous	2	А	
Ів	Base Current-Continuous	1	А	
Pc	Collector Power Dissipation @T <sub>C</sub> =25°C	25	W	
TJ	Junction Temperature	150	$^{\circ}$	
Tstg	Storage Temperature	-55~150	$^{\circ}$	







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#### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 25mA ; I <sub>B</sub> = 0	150			V			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 0.7A; I <sub>B</sub> = 0.07A			1.0	V			
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 150V ; I <sub>E</sub> = 0			10	μА			
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 6V; I <sub>C</sub> = 0			10	μА			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 0.7A; V <sub>CE</sub> = 10V	60						
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f= 1MHz		35		pF			
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>E</sub> = -0.2A ; V <sub>CE</sub> = 12V		15		MHz			
Switching Times									
t <sub>on</sub>	Turn-On Time			1.0		μS			
tstg	Storage Time	I <sub>C</sub> = 1A; I <sub>B1</sub> = -I <sub>B2</sub> = 0.1A; V <sub>CC</sub> = 20V; R <sub>L</sub> = 20 Ω		3.0		μS			
t <sub>f</sub>	Fall Time			1.5		μ <b>S</b>			

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